

# LC372100PP, PM, PT-10/20LV

# 2 MEG (262144 words × 8 bits) Mask ROM Internal Clocked Silicon Gate

# **Preliminary**

### Overview

The LC372100PP, LC372100PM and LC372100PT are 262,144-word  $\times$  8-bit organization (2,097,152-bit) mask programmable read only memories.

The LC372100PP-10, LC372100PM-10 and LC372100PT-10 feature an access time of 100 ns, an OE access time of 40 ns, and a standby current of 30  $\mu$ A, and are optimal for use in 5-V systems that require high-speed access.

The LC372100PP-20LV, LC372100PM-20LV and LC372100PT-20LV feature an access time of 200 ns, an OE access time of 80 ns, and a standby current of 4  $\mu$ A, and thus are optimal for use in 3-V systems that use batteries. Additionally, they provide high-speed access in 3.3-V systems (3.0 to 3.6 V) with a 150-ns access time and a 60-ns OE access time.

These ROMs adopt the JEDEC standard pin assignment which allows them to replace EPROM easily. To prevent bus line collisions in multi-bus microcontroller systems, pin 24 can be mask programmed to be either active high or active low.

### **Features**

- 262144 words × 8 bits organization
- · Power supply

LC372100PP, PM, PT-10:  $5.0 \text{ V} \pm 10\%$  LC372100PP, PM, PT-20LV: 2.7 to 3.6 V

• Fast access time (t<sub>AA</sub>, t<sub>CA</sub>)

LC372100PP, PM, PT-10: 100 ns (max.) LC372100PP, PM, PT-20LV: 200 ns (max.) 150 ns

 $(V_{CC} = 3.0 \text{ to } 3.6 \text{ V})$ 

• Operating current

LC372100PP, PM, PT-10: 70 mA (max.) LC372100PP, PM, PT-20LV: 20 mA (max.)

· Standby current

LC372100PP, PM, PT-10: 30 μA (max.) LC372100PP, PM, PT-20LV: 5 μA (max.)

- Full static operation (internal clocked type)
- Fully TTL compatible (5 V supply)
- 3 state outputs
- JEDEC standard pin configuration

· Package type

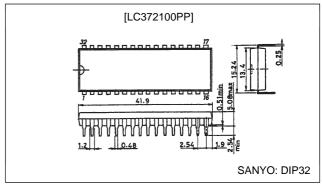
LC372100PP-10/20LV: DIP32 (600 mil) LC372100PM-10/20LV: SOP32 (525 mil)

LC372100PT-10/20LV: TSOP32 (8 mm × 20 mm)

# **Package Dimensions**

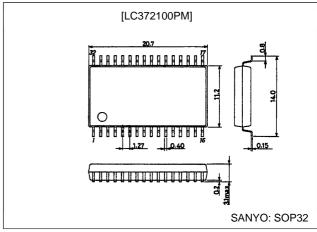
unit: mm

### 3192-DIP32

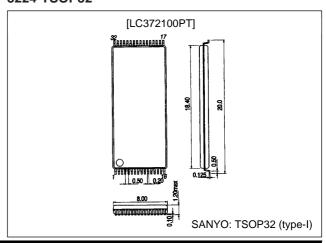


unit: mm

#### 3205-SOP32



unit: mm **3224-TSOP32** 

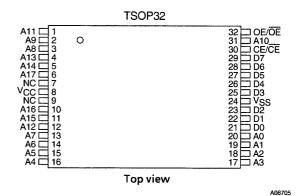


### **Pin Assignments**

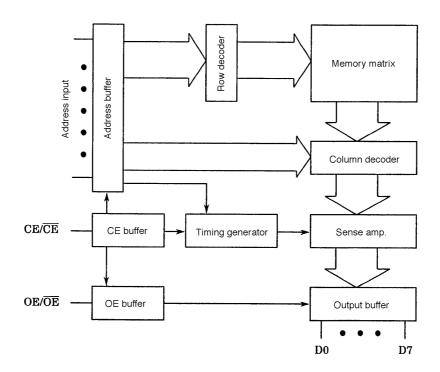
#### DIP32, SOP32 32 VCC 31 NC A16 2 30 A17 A15 3 A12 4 29 A14 5 28 A13 A6 6 27 AB 26 A9 25 A11 24 0E/0E 23 A10 25 CE\CE A0 12 21 D7 DO 13 20 D6 D1 14 19 D5 D2 15 18 D4 17 D3 Vss 16 Top view A03762

### **Pin Functions**

A0 to A17	Address input
D0 to D7	Data output
CE/CE	Chip enable input
OE/OE	Output enable input
V <sub>CC</sub>	Power supply
V <sub>SS</sub>	Ground



# **Block Diagram**



### **Truth Table**

CE/CE	OE/OE	Output	Current drain	
L/H	X	High-impedance	Standby mode	
H/L	L/H	High-impedance	Operating mode	
H/L	H/L	H/L DOUT Operating mode		

X: H or L level should be offered.

# **Specifications**

# Absolute Maximum Ratings \*1

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V <sub>CC</sub> max		-0.3 to +7.0	V
Supply input voltage	V <sub>IN</sub>		-0.3*2 to V <sub>CC</sub> + 0.3	V
Supply output voltage	V <sub>OUT</sub>		-0.3 to V <sub>CC</sub> + 0.3	V
Allowable power dissipation	Pd max	Ta = 25°C; Reference values for the SANYO DIP package	1.0	W
Operating temperature	Topr		0 to +70	°C
Storage temperature	Tstg		-55 to +125	°C

Note: 1. Permanent device damage may occur if Absolute Maximum Ratings are exceeded. Functional operation should be restricted to Recommended Operating Conditions.

# Input/Output Capacitance\* at Ta = 25°C, f = 1.0 MHz

Parameter Symbol		Conditions		Unit		
Farameter	Symbol	Conditions	min	typ	max	Offic
Input capacitance	C <sub>IN</sub>	V <sub>IN</sub> = 0 V; Reference values for the SANYO DIP package			8	pF
Output capacitance	C <sub>OUT</sub>	V <sub>OUT</sub> = 0 V; Reference values for the SANYO DIP package			10	pF

Note: \* This parameter is periodically sampled and not 100% tested.

### 3 V Operation

### DC Recommended Operating Ranges at Ta = 0 to +70°C

Parameter	Symbol	Conditions		Unit		
	Symbol	Conditions	min	typ	max	Onit
Supply voltage	V <sub>CC</sub> max		2.7	3.0	3.6	V
Input high level voltage	V <sub>IH</sub>		0.8 V <sub>CC</sub>		V <sub>CC</sub> + 0.3	V
Input low level voltage	V <sub>IL</sub>		-0.3		+0.4	V

# DC Electrical Characteristics at Ta = 0 to $+70^{\circ}$ C, $V_{CC} = 2.7$ to 3.6 V

Parameter Svm	Symbol	Conditions		- Unit		
Parameter Symbol		Conditions	min	typ	max	Offic
Operating supply current	I <sub>CCA1</sub>	$\overline{\text{CE}} = 0.2 \text{ V (CE} = \text{V}_{\text{CC}} - 0.2 \text{ V)}, \text{ V}_{\text{I}} = \text{V}_{\text{CC}} - 0.2 \text{ V}/0.2 \text{ V}$			15	mA
Operating supply current	I <sub>CCA2</sub>	$\overline{\text{CE}} = \text{V}_{\text{IL}} \text{ (CE = V}_{\text{IH}}), \text{ I}_{\text{O}} = 0 \text{ mA}, \text{ V}_{\text{I}} = \text{V}_{\text{IH}}/\text{V}_{\text{IL}}, \text{ f} = 5 \text{ MHz}$			20	mA
Standby supply current	I <sub>CCS1</sub>	<del>CE</del> = V <sub>CC</sub> - 0.2 V (CE = 0.2 V)			5 (0.5*)	μA
	I <sub>CCS2</sub>	CE = V <sub>IH</sub> (CE = V <sub>IL</sub> )			50 (10*)	μA
Input leakage current	ILI	$V_{IN} = 0$ to $V_{CC}$			±1.0	μA
Output leakage current	I <sub>LO</sub>	$\overline{\text{CE}}$ or $\overline{\text{OE}} = V_{\text{IH}}$ (CE or OE = $V_{\text{IL}}$ ), $V_{\text{OUT}} = 0$ to $V_{\text{CC}}$			±1.0	μA
Output high level voltage	V <sub>OH</sub>	$I_{OH} = -0.5 \text{ mA}$	V <sub>CC</sub> - 0.2			V
Output low level voltage	V <sub>OL</sub>	I <sub>OL</sub> = 0.5 mA			0.2	V

Note: \* Guaranteed at Ta = 25°C

# AC Characteristics at Ta = 0 to $+70^{\circ}C$ , $V_{CC} = 2.7$ to 3.6 V

Parameter	Symbol	Conditions		Unit		
	Symbol	Conditions	min	typ	max	Offic
Cycle time	t <sub>CYC</sub>		200 (150*2)			ns
Address access time	t <sub>AA</sub>				200 (150*2)	ns
CE access time	t <sub>CA</sub>				200 (150*2)	ns
OE access time	t <sub>OA</sub>				80 (60*2)	ns
Output hold time	t <sub>ОН</sub>		25			ns
Output disable time*1	t <sub>OD</sub> *1				50	ns

Note: 1. t<sub>OD</sub> is measured from the earlier edge of the  $\overline{\text{CE}}$  (CE) or  $\overline{\text{OE}}$ (OE)'s going high impedance. This parameter is periodically sampled and not 100% tested.

<sup>2.</sup>  $V_{IN}$  (min) = -3.0 V (pulse width  $\leq$  30 ns)

<sup>2.</sup> Guaranteed at  $V_{CC}$  = 3.0 to 3.6 V

# 5 V Operation

# DC Recommended Operating Ranges at Ta = 0 to +70°C

Parameter	Symbol	Conditions		Unit		
	Symbol	Conditions	min	typ	max	Onit
Supply voltage	V <sub>CC</sub> max		4.5	5.0	5.5	V
Input high level voltage	V <sub>IH</sub>		2.2		V <sub>CC</sub> + 0.3	V
Input low level voltage	V <sub>IL</sub>		-0.3		+0.6	٧

# DC Electrical Characteristics at Ta = 0 to $+70^{\circ}C$ , $V_{CC} = 5.0~V \pm 10\%$

Parameter Sym	Symbol	Conditions		Unit		
Parameter Symbol		Conditions	min	typ	max	Onit
Operating aupply aurrent	I <sub>CCA1</sub>	$\overline{\text{CE}} = 0.2 \text{ V (CE} = \text{V}_{\text{CC}} - 0.2 \text{ V)}, \text{ V}_{\text{I}} = \text{V}_{\text{CC}} - 0.2 \text{ V}/0.2 \text{ V}$			30	mA
Operating supply current	I <sub>CCA2</sub>	$\overline{\text{CE}} = \text{V}_{\text{IL}} \text{ (CE = V}_{\text{IH}}), \text{ I}_{\text{O}} = 0 \text{ mA}, \text{ V}_{\text{I}} = \text{V}_{\text{IH}}/\text{V}_{\text{IL}}, \text{ f} = 10 \text{ MHz}$			70	mA
Standby aupply aurrent	I <sub>CCS1</sub>	$\overline{CE} = V_{CC} - 0.2 \text{ V (CE} = 0.2 \text{ V)}$			30 (1.0*)	μA
Standby supply current Icc	I <sub>CCS2</sub>	CE = V <sub>IH</sub> (CE = V <sub>IL</sub> )			1.0 (300*)	mA (μA)
Input leakage current	ILI	$V_{IN} = 0$ to $V_{CC}$			±1.0	μA
Output leakage current	I <sub>LO</sub>	$\overline{\text{CE}}$ or $\overline{\text{OE}} = V_{\text{IH}}$ (CE or OE = $V_{\text{IL}}$ ), $V_{\text{OUT}} = 0$ to $V_{\text{CC}}$			±1.0	μA
Output high level voltage	V <sub>OH</sub>	$I_{OH} = -1.0 \text{ mA}$	2.4			V
Output low level voltage	V <sub>OL</sub>	I <sub>OL</sub> = 2.0 mA			0.4	V

Note: \* Guaranteed at Ta = 25°C

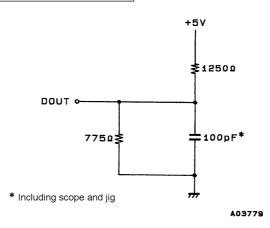
# AC Characteristics at Ta = 0 to +70°C, $V_{CC}$ = 5.0 V ±10%

Parameter	Symbol	Conditions		Unit		
		Conditions	min	typ	max	Offic
Cycle time	t <sub>CYC</sub>		100			ns
Address access time	t <sub>AA</sub>				100	ns
CE access time	t <sub>CA</sub>				100	ns
OE access time	t <sub>OA</sub>				40	ns
Output hold time	t <sub>OH</sub>		20			ns
Output disable time*	t <sub>OD</sub>				30	ns

Note: \*  $t_{OD}$  is measured from the earlier edge of the  $\overline{CE}$  (CE) or  $\overline{OE}$ (OE)'s going high impedance. This parameter is periodically sampled and not 100% tested.

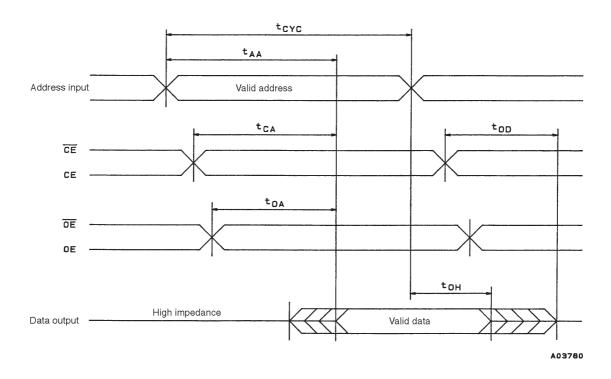
### **AC Test Conditions**

Input pulse levels	0.4 V to 0.8 V <sub>CC</sub> (3 V measurement), 0.4 V to 2.8 V (5 V measurement)
Input rise/fall time	5 ns
Input timing level	1.5 V
Output timing level	1.5 V
Output load	70 pF (3 V measurement) See figure (5 V measurement)



**Output Load (5 V measurement)** 

### **Timing Chart**



### **System Design Notes**

These LSIs adopt an internal synchronization technique in which operation is started by detecting changes in either the CE input or the address inputs. As a result, the output data immediately after power on is invalid. Once power has been applied, valid data is output after the application changes the value of either the CE input or at least one of the address inputs.

Another point due to the use of the ATD technique is that these LSIs are extremely sensitive to input noise. Applications must take precautions to provide stable input signals, both for the CE input and the address inputs, to prevent incorrect operation.

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